

## TO-92 Plastic-Encapsulate Transistors

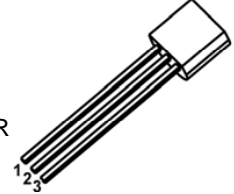
### 3DG3332 TRANSISTOR (NPN)

#### FEATURES

- High breakdown voltage
- Excellent  $h_{FE}$  linearity
- Large current capacity and wide ASO

#### TO-92

1. EMITTER
2. COLLECTOR
3. BASE



#### MAXIMUM RATINGS ( $T_A=25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Value	Unit
$V_{CBO}$	Collector-Base Voltage	180	V
$V_{CEO}$	Collector-Emitter Voltage	160	V
$V_{EBO}$	Emitter-Base Voltage	6	V
$I_C$	Collector Current -Continuous	0.7	A
$P_C$	Collector Power Dissipation	0.625	W
$R_{\theta JA}$	Thermal Resistance from Junction to Ambient	200	$^\circ\text{C/W}$
$T_J$	Junction Temperature	150	$^\circ\text{C}$
$T_{stg}$	Storage Temperature	-55~+150	$^\circ\text{C}$

#### ELECTRICAL CHARACTERISTICS ( $T_A=25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C=10\mu\text{A}, I_E=0$	180			V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C=1\text{mA}, I_B=0$	160			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E=10\mu\text{A}, I_C=0$	6			V
Collector cut-off current	$I_{CBO}$	$V_{CB}=120\text{V}, I_E=0$			0.1	$\mu\text{A}$
Emitter cut-off current	$I_{EBO}$	$V_{EB}=4\text{V}, I_C=0$			0.1	$\mu\text{A}$
DC current gain	$h_{FE(1)}$	$V_{CE}=5\text{V}, I_C=100\text{mA}$	100		400	
	$h_{FE(2)}$	$V_{CE}=5\text{V}, I_C=10\text{mA}$	80			
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C=250\text{mA}, I_B=25\text{mA}$			0.4	V
Base-emitter gUli fUjcb voltage	$V_{BE(sat)}$	$I_C=250\text{mA}, I_B=25\text{mA}$			1.2	V
Collector output capacitance	$C_{ob}$	$V_{CB}=10\text{V}, f=1\text{MHz}$		8		pF
Transition frequency	$f_T$	$V_{CE}=10\text{V}, I_C=50\text{mA}$		120		MHz
Turn-on Time	$t_{on}$	$V_{CC}=100\text{V}, I_C=300\text{mA}, I_{B1}=-I_{B2}=15\text{mA}$			0.05	$\mu\text{s}$
Storage Time	$t_{stg}$				1	$\mu\text{s}$
Fall Time	$t_f$				0.06	$\mu\text{s}$

#### CLASSIFICATION of $h_{FE(1)}$

Rank	R	S	T
Range	100-200	140-280	200-400

## TO-92 Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	3.300	3.700	0.130	0.146
A1	1.100	1.400	0.043	0.055
b	0.380	0.550	0.015	0.022
c	0.360	0.510	0.014	0.020
D	4.300	4.700	0.169	0.185
D1	3.430		0.135	
E	4.300	4.700	0.169	0.185
e	1.270 TYP		0.050 TYP	
e1	2.440	2.640	0.096	0.104
L	14.100	14.500	0.555	0.571
Φ		1.600		0.063
h	0.000	0.380	0.000	0.015

## TO-92 Suggested Pad Layout



### Note:

1. Controlling dimension: in millimeters.
2. General tolerance:  $\pm 0.05\text{mm}$ .
3. The pad layout is for reference purposes only.

### NOTICE

JCET reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to any product herein. JCET does not assume any liability arising out of the application or use of any product described herein.

TO-92 PACKAGE TAPING DIMENSION



Dimensions are in millimeter								
A1	A	T	P	P0	P2	F1	F2	W
4.5	4.5	3.5	12.7	12.7	6.35	2.5	2.5	18.0
W0	W1	W2	H	H0	D0	t1	t2	ΔP
6.0	9.0	1.0 MAX.	19.0	16.0	4.0	0.4	0.2	0



Package	Box	Box Size(mm)	Carton	Carton Size(mm)
TO-92	2000 pcs	333×162×43	20,000 pcs	350×340×250